Micron-scale gas detectors

Simulations

Heed – Magboltz – Maxwell – Garfield

Heed simulates ionisation patterns produced by charged particles and photons in a gas.

Magboltz computes electron transport tables for nearly arbitrary gas mixtures: drift velocity vectors, diffusion tensors, Townsend and attachment coefficients.

Maxwell is a finite element field calculation program.

Garfield uses the above to trace electrons and ions in gas-based detectors, computing signals.

History

- These programs were developed for the simulation of centimeter-scale gas-based detectors with a spatial resolution of ~100 μm.
- They have been used with success for the simulation of TPCs, drift tubes, CSCs ...
- Since a couple of years, they are also used for smaller scale detectors – generally with less success.
- This talk discusses the background to the problems that are encountered.

Simulation issues

Field calculations with finite element programs.

- Some small-scale detectors (e.g. GEMs) contain exposed dielectrics. Charge can accumulate on these leading to dynamic effects.
- Transport, and thus diffusion and gain, of electrons at small scales and in inhomogeneous fields.

Gain calculations in Penning mixtures.

Issues with field calculations

- Analytic fields are known for many 2D configurations.
 But the devices discussed in this meeting are 3D, frequently containing dielectric materials. Analytic solutions for these devices are very rare.
- A popular way out is to use the finite element method:
 - almost any geometry;
 - dielectrics;
 - commercial software;
 - graphical user interfaces ...



The price to pay for finite elements

- Finite element programs focus on the wrong thing: they solve the potential V, but we do not really need it:
 - quadratic shape functions do a fair job at approximating $V \approx \log(r)$ potentials;
 - potentials are continuous.
- *E* is what we use, but:
 - Solution gradients of quadratic shape functions are linear and not suitable to approximate our $E \approx 1/r$ fields with, left alone $E \approx 1/r^2$ fields;
 - electric fields are discontinuous;
 - ~50 % accuracy in high-field areas is common.

Food for thought ...

- The Finite Element Method is a very useful tool which can make a good engineer better, but it can make a bad engineer dangerous. [Robert D. Cook, Professor of Mechanical Engineering University of Wisconsin, Madison]
- One should wonder what the Finite Element Method cam do in the hands of a physicist !

Field calculations – way out

- Currently, a plausible way out seems to be the use of the integral equation or boundary element method.
- These methods place charges outside the problem domain and integrate the field using correct 3D expressions: no discontinuities, good approximation of small scale structures.
- But ... such programs are not widely available. One option would be to use a program produced recently by a group in India (Supratik Mukhopadhyay et al.).

Dynamic effects

- One detailed study of dynamic effects that I am aware of was done by Vitali Tikhonov (2002).
- He used an iterative approach:
 - finite element calculation of the GEM field;
 - tracking of electrons to determine surface charges;
 - surface charges added to the finite element model;
 - iteration until convergence achieved.
- Difficulties:
 - surface conductivity not well established;
 - all problems of the finite element approach;
 - laborious.

Issues with transport

- In e.g. argon-based gas mixtures, the mean free path is a few microns – i.e. comparable to the size of elements of the detector.
- Since the field may well vary on the scale of microns, the traditional statistical approach reaches the limits of its applicability.
- Instead, a Magboltz-like stepping algorithm with inhomogeneous field needs to be developed.

Amadeo Avogadro (1776-1856)

Distances in gases

Number of Ar atoms in a cm³:

- Avogadro's number:
- Atomic weight of Ar:
- Density of Ar:
- Loschmidt's number:

6.022 10^{23} atoms/mole ÷ 40 g/mole × 1.782 10^{-3} g/cm³ = $\mathscr{L} = 2.7 \ 10^{19}$ atoms/cm³

Distance between neighbouring Ar atoms: $\frac{4}{3}\pi r^3 \times 2.710^{19} = 1:$ $d \approx 5 \text{ nm}$



Josef Loschmidt (1821-1895)



Cross section of argon

Cross section in a hard-sphere model:

- Radius: 70 pm (http://www.webelements.com)
- Surface: $\sigma = \pi (70 \, 10^{-10} \, \text{cm})^2 \approx 1.5 \, 10^{-16} \, \text{cm}^2$

Measured cross sections, as used by Magboltz:



Mean free path in argon

- Mean free path for an electron ?
 - An electron hits all atoms of which the centre is less than a cross section radius from its path.
 - **•** Over a distance *L*, the electron hits $\mathcal{L}\sigma L$ atoms.
 - ► Hence, the mean free path is $\lambda_e = 1/(\mathscr{L}\sigma) \approx 2 \ \mu m$.
 - Much larger than the distance between atoms, 5 nm !

Scale \gg mean free path (> 1 mm)

- For practical purposes, electrons from a given starting point reach the same electrode – but with a spread in time and gain.
- Electrons transport is treated by:
 - integrating the equation of motion, using the Runge, Kutta, Fehlberg method, to obtain the path;
 - integrating the diffusion and Townsend coefficients to obtain spread and gain.
- This approach is adequate for TPCs, drift tubes etc.

Analytic integration

Example: a TPC read-out cell



Scale > mean free path (100 μ m - 1 mm)

- Electrons from a single starting point may end up on any of several electrodes.
- Calculations use Monte Carlo techniques, based on the mean drift velocity and the diffusion tensor computed by microscopic integration of the equation of motion in a constant field. Gain depends on the path.
- This approach is adequate as long as the drift field is locally constant – a reasonably valid assumption in a Micromegas but less so in a GEM.

Analytic vs Monte Carlo

 Analytic integration
 Runge-Kutta-Fehlberg technique;
 automatically adjusted step size;
 optional integration of diffusion, multiplication and losses.

 Monte Carlo integration
 non-Gaussian in accelerating, divergent and convergent fields;
 step size to be set by user.

[Figures made by Gilles Barouch, CEA]



Diffusion

Diffusion is not necessarily a Gaussian process, as illustrated here for a radial flow at constant mobility: $\dot{x} = \mu E_{x}, \dot{y} = \mu E_{y}$ Virtually harmless for converging flow, e.g. on approach of anode wires. Makes Gaussian formulae inadequate for diverging flow as found in GEMs.



[In collaboration with Gabriele Croci]

Scale ~ mean free path (1-100 μ m)

- Field variations during the free flight between collisions, affect the path – which may therefore no longer be parabolic.
- The only viable approach here seems to be a complete microscopic simulation of the transport processes, taking local field variations into account.
- This method, still to be written, should be based on the Magboltz program.

Issues regarding the gain

- Townsend coefficients as such are computed with fair accuracy by Magboltz.
- But in several gas mixtures, the gain is (grossly) underestimated if one integrates the Townsend coefficient as computed by Magboltz.
- The discrepancy is often due to the Penning effect: excited states of gas A ionise molecules of gas B. Excitation rates nearly always exceed ionisation rates and the effect, when allowed, has a major impact.

Gain in Ar $-iC_4H_{10}$ (1-5%)



[Plot: David Attié, CEA Saclay]

Details of the Magboltz output

Example: 5 % iC_4H_{10} at E = 60 kV/cm Isobutane: Argon: Excitations: Excitations: 11.55 eV (S): 12 GHz ▶ 7.4 eV: 19 GHz 13.0 eV (P): 12 GHz ▶ 9.7 eV: 5 GHz 14.0 eV (D): 4 GHz ▶ 17.0 eV: 0.4 GHz Ionisation: Ionisation: 12 GHz > 10.67 eV: 9 GHz > 15.7 eV: ▶ If all excited Ar atoms ionise iC_4H_{10} , the ionisation rate

goes from 21 GHz to 49 GHz, more than doubling the Townsend coefficient.

Penning transfer rate

| Comparing at 6 | 0 kV/cm: | |
|----------------|--------------|-------------|
| Measured: | gain ~ 1800, | α ~ 1500/cm |
| Calculated: | gain ~ 300, | α ~ 1140/cm |
| (Magboltz: | | α ~ 1150/cm |

This translates to a 25 % Penning transfer rate, in line with commonly quoted figures for such mixtures.

At present, there are few solid theoretical predictions of the Penning transfer rate. Ar-CH₄



Only the, relatively infrequent, argon-D excitation can lead to a Penning effect.

Gain in Ar – CH₄ (6-10%)



[Plot: David Attié, CEA Saclay]

Penning transfers in the Alice TPC

In 90 % Ne + 10 % CO₂, apparently 40 % of the Ne^{*} ionise CO₂, enhancing the gain by a factor 2-5 !



Gain – approach

Magboltz produces tables of excitation rates as part of its output.

Pending theoretical estimates of the Penning transfer rates, the transfer rate will have to be obtained from measurements.

Conclusion

- It is reasonably clear how the current difficulties with simulations should be addressed.
- Work in some areas, e.g. transport at the 100 µm scale and simplification of the use of Penning transfers rates, is in progress.
- ► In other domains, e.g. transport at the 10 µm scale and boundary element methods, needs to be started.

Backup slides

Penning effect at 80 kV/cm

- Example: 5 % iC_4H_{10} at E = 80 kV/cm
- isobutane:
 - Excitations:
 - ▶ 7.4 eV: 22 GHz
 - ▶ 9.7 eV: 7 GHz
 - ▶ 17.0 eV: 0.9 GHz
 - Ionisation:
 - 10.67 eV: 14 GHz

- argon:
 - Excitations:
 - 11.55 eV (S): 17 GHz
 - 13.0 eV (P): 21 GHz
 - 14.0 eV (D): 7 GHz
 - Ionisation:
 - 15.7 eV: 26 GHz
- ► If all excited Ar atoms ionise iC_4H_{10} , the ionisation rate goes from 40 GHz to 85 GHz, more than doubling the Townsend coefficient !